- Package Options include Plastic Small Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs
- Dependable Texas Instruments Quality and Reliability

### description

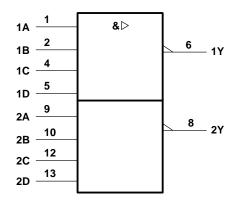
These devices contain two independent 4-input NAND buffer gates. They perform the Boolean functions  $Y = \overline{A} \cdot B \cdot C \cdot D$  or  $Y = \overline{A} + \overline{B} + \overline{C} + \overline{D}$  in positive logic.

The SN54ALS40A is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The SN74ALS40A is characterized for operation from 0°C to 70°C.

# FUNCTION TABLE (each gate)

	INP	OUTPUT		
Α	В	С	D	Υ
Н	Н	Н	Н	L
L	Χ	Χ	Χ	Н
Х	L	Χ	Χ	Н
Х	Χ	L	Χ	Н
Х	Χ	Χ	L	Н

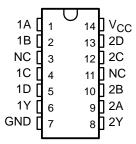
# logic symbol†



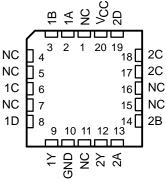
<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, and N packages.

#### SN54ALS40A . . . J PACKAGE SN74ALS40A . . . D OR N PACKAGE (TOP VIEW)

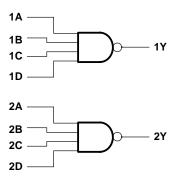


# SN54ALS40A . . . FK PACKAGE (TOP VIEW)



NC-No internal connection

## logic diagram (positive logic)



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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC</sub>		7 V
Input voltage		7 V
	SN54ALS40A	
	SN74ALS40A	0°C to 70°C
Storage temperature range		. −65°C to 150°C

#### recommended operating conditions

		SN54ALS40A		SN74ALS40A			UNIT	
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
٧ <sub>IH</sub>	High-level input voltage	2			2			V
V <sub>IL</sub>	Low-level input voltage			0.7			0.8	V
IOH	High-level output current			-1			-2.6	mA
loL	Low-level output current			12			24	mA
T <sub>A</sub>	Operating free-air temperature	-55		125	0		70	°C

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		SN	SN54ALS40A			SN74ALS40A		
			MIN	TYP†	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT
VIK	V <sub>CC</sub> = 4.5 V,	I <sub>I</sub> = –18 mA			-1.5			-1.5	V
	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V <sub>CC</sub> -2			V <sub>CC</sub> -2			
Vон	V <sub>CC</sub> = 4.5 V,	I <sub>OH</sub> = -1 mA	2.3	3.3					V
	V <sub>CC</sub> = 4.5 V,	I <sub>OH</sub> = −2.6 mA				2.4	3.2		
V <sub>OL</sub>	V <sub>CC</sub> = 4.5 V,	I <sub>OL</sub> = 12 mA		0.25	0.4		0.25	0.4	
	V <sub>CC</sub> = 4.5 V,	I <sub>OL</sub> = 24 mA					0.35	0.5	V
lį	$V_{CC} = 5.5 \text{ V},$	V <sub>I</sub> = 7 V			0.1			0.1	mA
lН	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 2.7 V			20			20	μΑ
I <sub>IL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.4 V			-0.1			-0.1	mA
10 <sup>‡</sup>	$V_{CC} = 5.5 \text{ V},$	V <sub>O</sub> = 2.25 V	-30		-112	-30		- 112	mA
ICCH	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0 V		0.43	0.8		0.43	8.0	mA
ICCL	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 4.5 V		2.4	3.9		2.4	3.9	mA

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25 \text{ C}$ .

### switching characteristics (see Note 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5 \text{ V},$ $C_L = 50 \text{ pF},$ $R_L = 500 \Omega,$ $T_A = 25^{\circ}C$ 'ALS40A TYP	C <sub>L</sub>	= 50 p = 500 = MIN t	Ω, o MAX	·	UNIT
<sup>t</sup> PLH	Δ m) /		5	2	10	2	8	20
<sup>t</sup> PHL	Any	Ţ	5	2	10	2	7	ns

NOTE 1: Load circuit and voltage waveforms are shown in Section 1.



<sup>‡</sup> The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS

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